

# **EMP104**

#### ISSUED DATE: 07-12-04

#### **FEATURES**

- 5.0 6.5 GHz Operating Frequency Range
- 33.0dBm Output Power at 1dB Compression
- 17.0 dB Typical Small Signal Gain
- -40dBc OIMD3 @Each Tone Pout 22dBm

#### **APPLICATIONS**

- Point-to-point and point-to-multipoint radio
- Military Radar Systems

5.0 – 6.5 GHz Power Amplifier MMIC

Dimension: 2200um X 3230um Thickness: 65um <u>+</u> 15um



Caution! ESD sensitive device.

### ELECTRICAL CHARACTERISTICS (Ta = 25 °C, 50 ohm, VDD=10V, IDQ=1000mA)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	5.0		6.5	GHz
P1dB	Output Power at 1dB Gain Compression	32.0	33.0		dBm
Gss	Small Signal Gain	15.0	17.0		dB
OIMD3	Output 3 <sup>rd</sup> Order Intermodulation Distortion @∆f=10MHz, Each Tone Pout 22dBm		-40		dBc
Input RL	Input Return Loss		-8	-6	dB
Output RL	Output Return Loss		-6		dB
ldss	Saturate Drain Current $V_{DS} = 3V, V_{GS} = 0V$		1680		mA
V <sub>DD</sub>	Power Supply Voltage		10		V
Rth	Thermal Resistance (Au-Sn Eutectic Attach)		7		°C/W
Tb	Operating Base Plate Temperature	- 35		+ 80	°C

#### **ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION<sup>1,2</sup>**

SYMBOL	CHARACTERISTIC	VALUE	
V <sub>DS</sub>	Drain to Source Voltage	10V	
$V_{GS}$	Gate to Source Voltage	- 4V	
I <sub>DD</sub>	Drain Current	ldss	
I <sub>GSF</sub>	Forward Gate Current	35 mA	
P <sub>IN</sub>	Input Power	@ 3dB compression	
Т <sub>СН</sub>	Channel Temperature	150°C	
T <sub>STG</sub>	Storage Temperature	-65/150°C	
Ρ <sub>T</sub>	Total Power Dissipation	17W	

1. Operating the device beyond any of the above rating may result in permanent damage.

2. Bias conditions must also satisfy the following equation  $V_{DS}*I_{DS} < (T_{CH} - T_{HS})/R_{TH}$ ; where  $T_{HS}$  = ambient temperature

Specifications are subject to change without notice. Excelics Semiconductor, Inc. 310 De Guigne Drive, Sunnyvale, CA 94085 Phone: 408-737-1711 Fax: 408-737-1868 Web: www.excelics.com

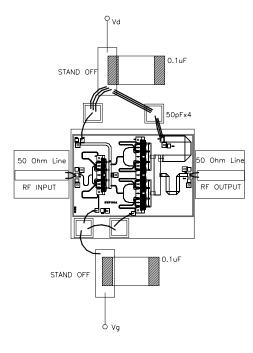


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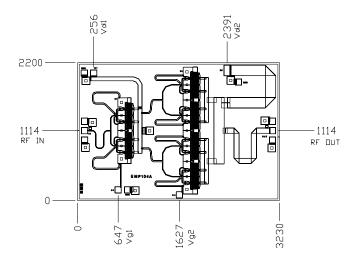
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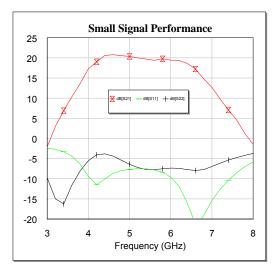
### **ASSEMBLY DRAWING**



### **CHIP OUTLINE**

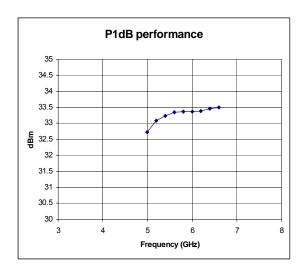


All Dimensions in Microns



TYPICAL PERFORMANCE

Data measured @ Vd=10V, Id=950mA



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